SLFS001A - JUNE 1985 - REVISED APRIL 1988

- Adjustable Gain to 400 Typ
- No Frequency Compensation Required
- Low Noise . . . 3 μV Typ V_n

description

This device is a monolithic two-stage video amplifier with differential inputs and differential outputs. It features internal series-shunt feedback that provides wide bandwidth, low phase distortion, and excellent gain stability. Emitterfollower outputs enable the device to drive capacitive loads. All stages are current-source biased to obtain high common-mode and supply-voltage rejection ratios.

The differential gain is typically 400 when the gain adjust pins are connected together, or amplification may be adjusted for near 0 to 400 by the use of a single external resistor connected between the gain adjustment pins A and B. No external frequency-compensating components are required for any gain option.

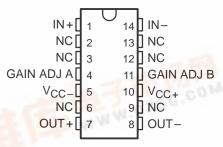
The device is particularly useful in magnetic-tape or disk-file systems using phase or NRZ encoding and in high-speed thin-film or plated-wire memories. Other applications include general-purpose video and pulse amplifiers.

The device achieves low equivalent noise voltage through special processing and a new circuit layout incorporating input transistors with low base resistance.

The TL592B is characterized for operation from 0°C to 70°C.

D8^T OR P PACKAGE

D14[†] OR N PACKAGE (TOP VIEW)



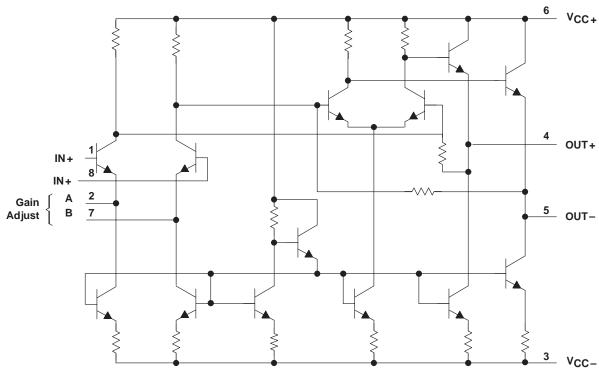
†D8 and D14 are the codes to differentiate the 8-pin and 14-pin versions, respectively.

symbol

TL592B DIFFERENTIAL VIDEO AMPLIFIER

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schematic



Pin numbers are for D8 and P packages.

absolute maximum ratings over operating free-air temperature (unless otherwise noted)

Supply voltage, V _{CC+} (see Note 1)	8 V
Supply voltage, V _{CC}	8 V
Differential input voltage	±5 V
Voltage range, any input	V _{CC+} to V _{CC-}
Output current	10 mA
Continuous total power dissipation	See Dissipation Rating Table
Operating free-air temperature range	0°C to 70°C
Storage temperature range	65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

NOTES: 1. All voltage values except differential input voltages are with respect to the midpoint between V_{CC+} and V_{CC-} .

DISSIPATION RATING TABLE

PACKAGE	T _A ≤ 25°C POWER RATING	DERATING FACTOR	DERATE ABOVE T _A	T _A = 70°C POWER RATING	
D8	530 mW	5.8 mW/°C	59°C	464 mW	
D14	530 mW	N/A	N/A	530 mW	
N	530 mW	N/A	N/A	530 mW	
Р	530 mW	N/A	N/A	530 mW	



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recommended operating conditions

	MIN	NOM	MAX	UNIT
Supply voltage, V _{CC+}	3	6	8	V
Supply voltage, V _{CC} _	-3	-6	-8	V
Operating free-air temperature, T _A	0		70	°C

electrical characteristics at specified free-air temperature, V_{CC \pm} = \pm 6 V, R_L = 2 k Ω (unless otherwise noted)

PARAMETER		TEST FIGURE TEST CONDITIONS†		TA	MIN	TYP	MAX	UNIT	
۸. ه	Large-signal differential	1	V _{OPP} = 3 V,	$R_L = 2 k\Omega$,	25°C	300	400	500	V/V
AVD	voltage amplification	lification $R_{AB} = 0$	$R_{AB} = 0$			250		600	V/V
A _{VD2}	Large-signal differential voltage amplification	1	$V_{OPP} = 3 \text{ V},$ $R_{AB} = 1 \text{ k}\Omega$	$R_L = 2 k\Omega$,	25°C		13		V/V
BW	Bandwidth (-3 dB)	2	V _{OPP} = 1 V,	$R_{AB} = 0$	25°C		50		MHz
IIO	Input offset current				25°C		0.4	5	
					0°C to 70°C			6	μΑ
l.=	Input bias current				25°C		9	30	μΑ
IВ	input bias current				0°C to 70°C			40	
V/105	Common-mode input	3			25°C	±1			V
VICR	voltage range	3			0°C to 70°C	±1			V
Voc	Common-mode output voltage	1	R _L = ∞		25°C	2.4	2.9	3.4	V
		4	$V_{ID} = 0,$	R _{AB} = ∞,	25°C		0.35	0.75	V
V00	Output offset voltage	1	R _L = ∞		0°C to 70°C			1.5	
\ /	Peak-to-peak output voltage swing	1	$R_L = 2 k\Omega$,		25°C	3	4		V
VOPP				$R_{AB} = 0$	0°C to 70°C	2.8			
	Innut registeres		V 4.V	D 0	25°C		4		kΩ
rį	Input resistance		V _{OD} = 1 V,	$R_{AB} = 0$	0°C to 70°C		3.6		K22
r _O	Output resistance				0°C to 70°C			30	Ω
Ci	Input capacitance				25°C		5		pF
	Common-mode rejection ratio	3	$V_{IC} = \pm 1 V$, $R_{AB} = 0$	f = 100 kHz	25°C	60	86		dB
01.155				f = 5 MHz			60		
CMRR				f = 100 kHz	0°C to 70°C	50			
				f = 5 MHz			60		
l	Supply voltage rejection ratio (ΔV _{CC} /ΔV _{IO})	4	$\Delta V_{CC} + = \pm 0.5 \text{ V},$	R _{AB} = 0	25°C	50	70		4D
ksvr			$\Delta V_{CC} - = \pm 0.5 \text{ V},$		0°C to 70°C	50			dB
Vn	Broadband equivalent input noise voltage	4	BW = 1 kHz to 10 MHz		25°C		3		μV
^t pd	Propagation delay time	2	$\Delta V_O = 1 V$		25°C		7.5		ns
t _r	Rise time	2	$\Delta V_O = 1 V$		25°C		10.5		ns
I _{sink(max)}	Maximum output sink current		V _{ID} = 1 V,	V _O = 3 V		3	4		mA
Icc	Supply current		No load,	No signal	25°C 0°C to 70°C		18	24 27	mA

[†] RAB is the gain-adjustment resistor connected between gain-adjust pins A and B. If not specified for a particular parameter, its value is irrelevant to that parameter.



PARAMETER MEASUREMENT INFORMATION

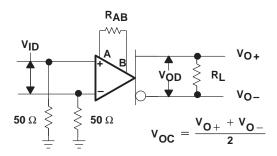


Figure 1

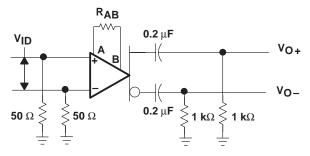


Figure 2

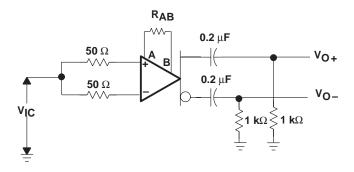


Figure 3

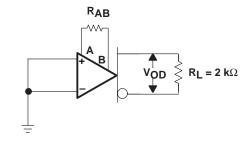
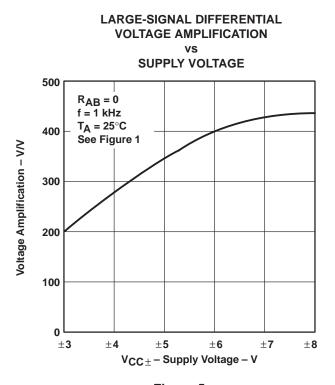


Figure 4



TYPICAL CHARACTERISTICS



LARGE-SIGNAL DIFFERENTIAL
VOLTAGE AMPLIFICATION
VS
CAIN AD HISTMENT RESISTANCE

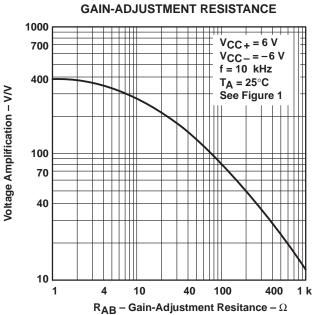


Figure 6

Figure 5

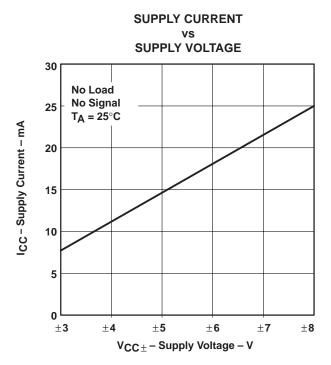


Figure 7



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